

Design from scratch of a Chebyshev bandpass filter

Microstrip lines are used instead of the usual capacitors/inductors as we deal with HF signals, which means their wavelength is similar to the length of the circuit. Therefore, voltages and currents are not constant along the line, and according to the transmission line length, a capacitor, resonator, inductor can be designed.

For a bandpass filter, 3 main configuration are mainly used :

- Chebyshev
- Butterworth
- Bessel

Chebyshev

Chebyshev grants a more violent slope when cutting frequencies are reached. On the other hand, we have to deal with ripples in the bandwidth. It is widely used in HF as we need fast transitions between cutoff band and pass band.

The idea of a Chebyshev filter is to start from a low pass filter and then go to a bandpass filter.

Here is the transfer function of a Chebyshev bandpass filter :

$$G_n(\omega) = |H_n(\omega)| = \frac{1}{\sqrt{1 + \varepsilon^2 T_n^2\left(\frac{\omega}{\omega_c}\right)}}$$

- Epsilon is the ripple
- Tn is the Chebyshev polynomial of n order
- Wc is the angular cutoff frequency

Butterworth

It has a longer transition between pass band and stop band, however, there is no ripples

La fonction de transfert d'un passe bas-Butterworth est donnée par :

$$G_n(\omega) = |H_n(j\omega)| = \frac{1}{\sqrt{1 + (\omega/\omega_c)^{2n}}}$$

Bessel

It is the slowest one concerning the transition between pass band and stop band.

In our case, we want a really fast transition, so Chebyshev seems to be what we need here.

Hence, let's go for the design of a bandpass Chebyshev filter

What we know :

- $F_0 = 1.9\text{GHz}$

- $\text{BW} = 10\text{MHz}$

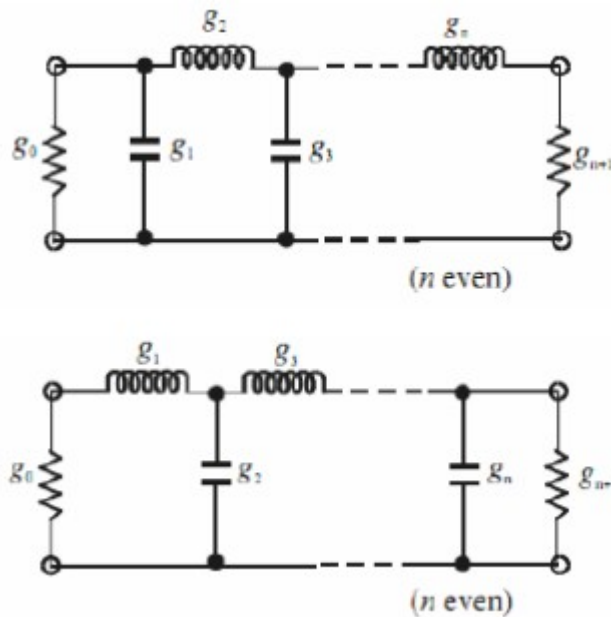
-pass band ripple 0.5 dB

-Impédance source : 50 Ohms

Design of the normalized low pass filter

It is the 1st step. The goal is to find the g coefficient of the Chebyshev low pass. Normalized means that $R_L = R_S = 1\text{ Ohm}$ and $\omega_c = 1\text{ rad/s}$

From there, some formulas allow to find these g coefficients



These coefficient, as

shown on both schematic are in fact the values of the capacitors/inductors of the normalized filter.

Usually, you don't need to recalculate these g coefficients. Instead, some tables are provided online, where according to your filter order and the bandwidth ripple, you can read the g coefficients.

For those who are interested anyway in seeing the calculations to find these g coefficients, you'll find the formulas on the next page.

$$\beta = \ln \left(\coth \frac{G_r}{17.37} \right) \quad \dots\dots 1$$

Where G_r = ripples in pass band

$$\gamma = \sinh \frac{\beta}{2n} \quad \dots\dots 2$$

$$a_K = \sin \left[\frac{(2^K - 1)\pi}{2n} \right] \quad \dots\dots 3$$

$K = 1, 2, 3, \dots\dots n$

$$b_K = \gamma^2 + \sin^2 \left[\frac{K\pi}{n} \right] \quad \dots\dots 4$$

$K = 1, 2, 3, \dots\dots n$

$$g_0 = 1, g_1 = \frac{2a_1}{\gamma} \quad \dots\dots 5$$

$$g_K = \frac{4a_{K-1} a_K}{b_{K-1} g_{K-1}} \quad \dots\dots 6$$

$K = 2, 3, 4, 5, \dots\dots n$

$$g_{m+1} = 1 \quad \text{if } n \text{ is odd} \quad \dots\dots 7$$

$$g_{m+1} = \coth^2 \left[\frac{\beta}{4} \right] \quad \text{if } n \text{ is even} \quad \dots\dots 8$$

One of the table I mentionned before, with 0.5 dB of ripple :

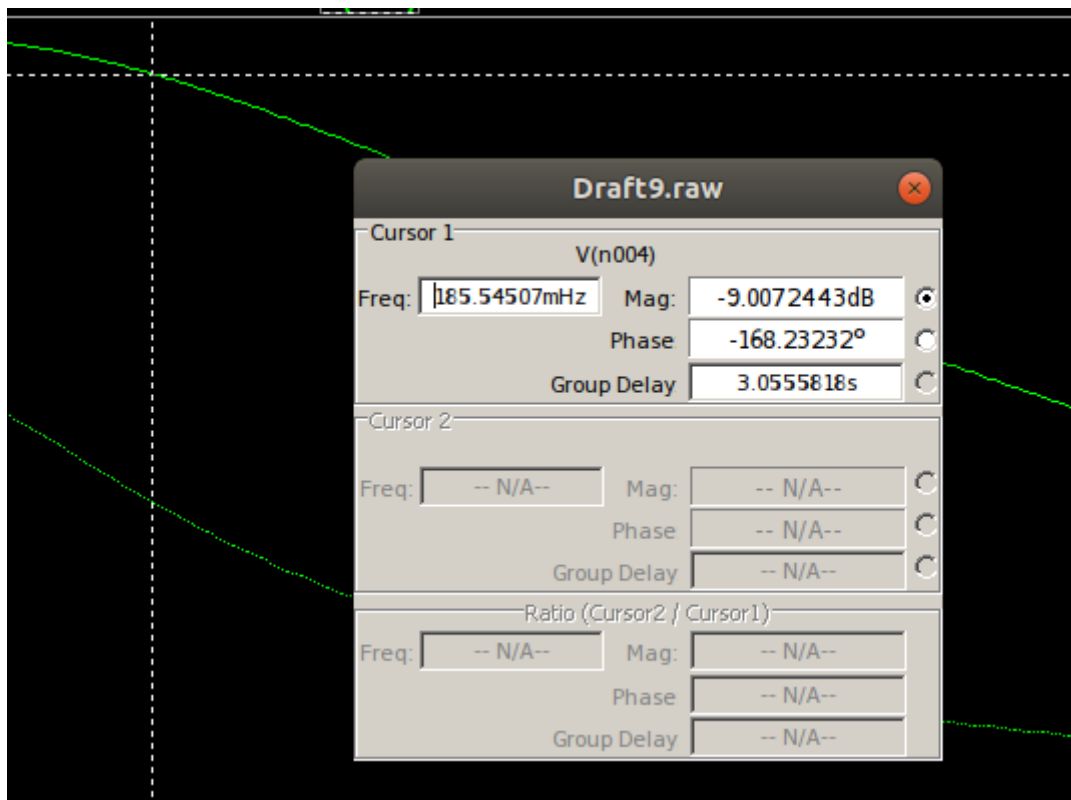
Normalized Chebyshev element values, 0.5 dB ripple*

Capacitor Input, $R_S=R_L=1 \Omega$, $f=1$ rad/sec										
Order	C1	L2	C3	L4	C5	L6	C7	L8	C9	R _{Load}
2	1.4029	0.7071								0.5040
3	1.5963	1.0967	1.5963							1
4	1.6704	1.1926	2.3662	0.8419						0.5040
5	1.7058	1.2296	2.5409	1.2296	1.7058					1
6	1.7254	1.2478	2.6064	1.3136	2.4759	0.8696				0.5040
7	1.7373	1.2582	2.6383	1.3443	2.6383	1.2582	1.7373			1
8	1.7451	1.2647	2.6565	1.3590	2.6965	1.3389	2.5093	0.8795		0.5040
9	1.7505	1.2690	2.6678	1.3673	2.7240	1.3673	2.6678	1.2690	1.7505	1
	L1	C2	L3	C4	L5	C6	L7	C8	L9	R _{Load}
Inductor Input, $R_S=R_L=1 \Omega$, $f=1$ rad/sec										

This table comes from the rfcafe.com website. We can notice the L_i and C_i values, as well as the R_{load} value which are all normalized. So for us, here are the capacitors and inductors values, with a Tee structure : $L1 = 1.705$ H, $C2 = 1.2690$ F and $L3 = 2.6678$ H .

You'll also notice that for even values of n , R_{load} is not 1. [rfcafe](http://rfcafe.com) says that a Chebyshev filter of an even order is not designable when $R_{load} = 1$ Ohm.

Let's draw the schematic on LTSpice, and look at the cutoff frequency, for example.



Racall : $Wc = 2 \cdot \pi \cdot fc$. Ici, $Wc = 1$, donc $fc = 159\text{mHz}$ (theorical value)
 We looked at $Gbw - 3\text{dB}$ (1st order filter) to see the cutoff frequency of the low pass.
 We can see that the simulated value is quite close of the calculated one.

From low pass to bandpass

After that, each big component of this low pass is cut in two smaller components : one inductor and one capacitor. These 2 new components ($n=3$, so 6 in total) will be in series-parallel-series (a Tee structure).

Formulas to find the values of the smaller components :

For the serial combination,

$$L_s = \frac{\xi \kappa Z_0}{\omega_0 \Delta}, \quad C_s = \frac{\Delta}{\xi \kappa \omega_0 Z_0} \quad \dots 9$$

And for the parallel combination.

$$C_p = \frac{\xi \kappa}{\omega_0 Z_0 \Delta}, \quad L_p = \frac{\Delta Z_0}{\xi \kappa \omega_0} \quad \dots 10$$

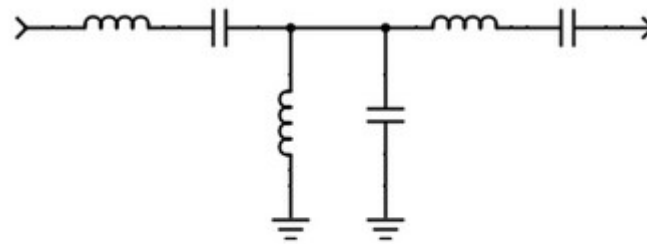
each couple of L_s/C_s and C_p/L_p corresponds to a big inductor/capacitor of the low pass.

With « s » standing for « serial » and « p » standing for parallel.

W_0 is given by $\sqrt{w_1 \cdot w_2}$ (corresponding to the 2 cutoff angular frequencies), and $\Delta = (w_2 - w_1)/w_0$.

We did the job of a lot of calculators that you can find online, which compute Chebyshev bandpass filers.

Still with LTSpice, let's we are going to simulate such a filter. A calculator is used.
Let's use a Tee structure.



First element : series

Chebyshev Bandpass Filter
www.changpuak.ch/electronics/chebyshev_bandpass.php
Version : 11. Jan 2014

Center Frequency : 1900 MHz
Bandwidth : 10 MHz
Passband Ripple : 0.5 dB
System Impedance : 50 Ohm
Order of Filter : 3

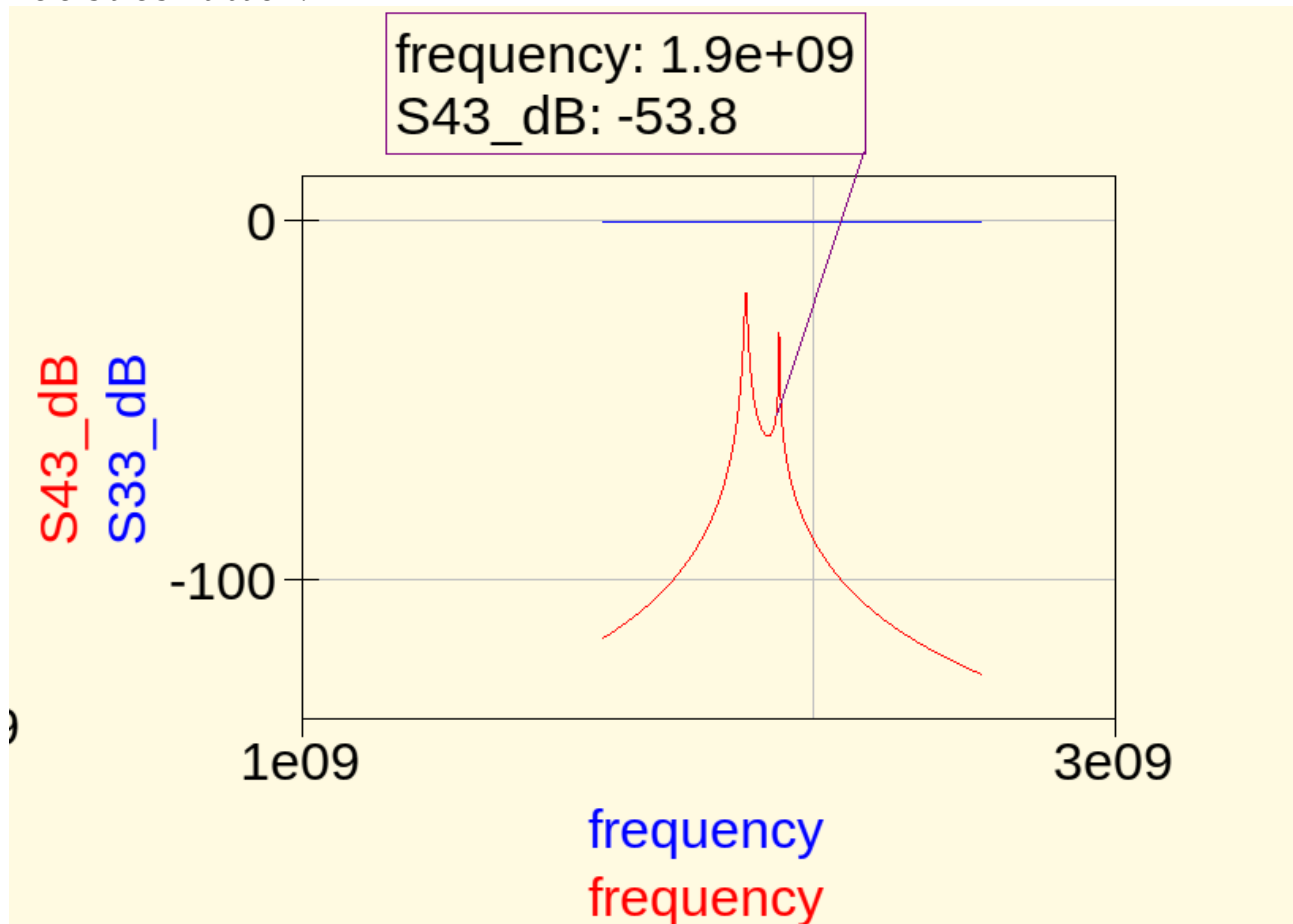
Element 1 , Orientation : series
C = 0.006 pF, L = 1270.32 nH
Element 2 , Orientation : shunt
C = 349.084 pF, L = 0.02 nH
Element 3 , Orientation : series
C = 0.006 pF, L = 1270.32 nH

Appendix : Prototype G values
G[1] : 1.5963313673878847
G[2] : 1.0966806950596955
G[3] : 1.5963313683049023

We just have to give the input and output impedance, the passband ripple, the order, center frequency and that's all.

This time, we are not in low frequency anymore, so let's use the Qucs software to see how well waves are being transmit

Here is the simulation :



Clearly, we can see that it is not good at all. The very thin bandwidth is responsible for this. Let's improve the bandwidth to let's say 100 MHz.

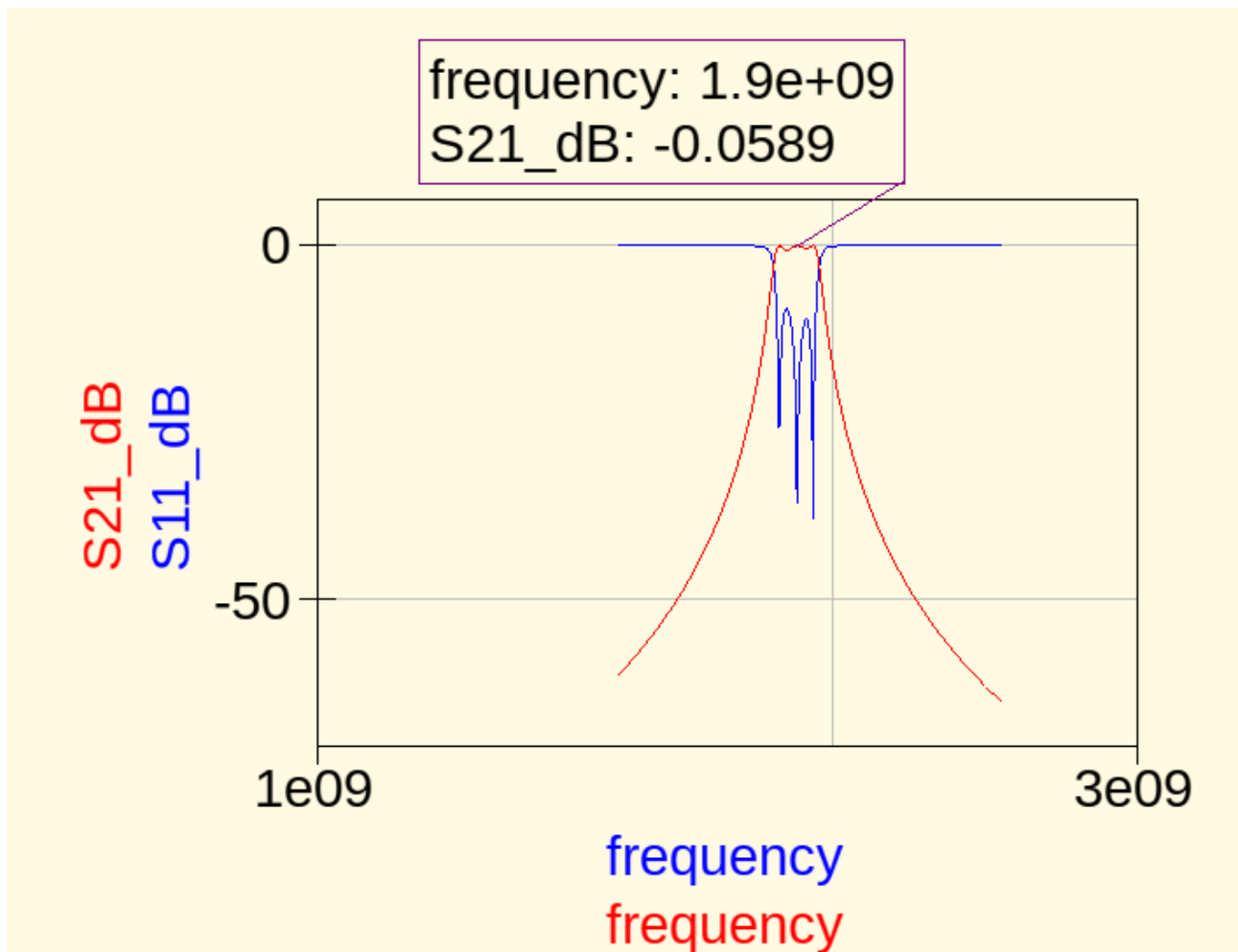
DESIGN DATA FOR YOUR BANDPASS

Chebyshev Bandpass Filter
www.changuak.ch/electronics/chebyshev_bandpass.php
Version : 11. Jan 2014

Center Frequency : 1900 MHz
Bandwidth : 100 MHz
Passband Ripple : 0.5 dB
System Impedance : 50 Ohm
Order of Filter : 3

Element 1 , Orientation : series
C = 0.055 pF, L = 127.032 nH
Element 2 , Orientation : shunt
C = 34.908 pF, L = 0.201 nH
Element 3 , Orientation : series
C = 0.055 pF, L = 127.032 nH

Appendix : Prototype G values
G[1] : 1.5963313673878847
G[2] : 1.0966806950596955
G[3] : 1.5963313683049023



It is well better. A larger bandwidth does not influence the gain.

Circuit résonnant LC

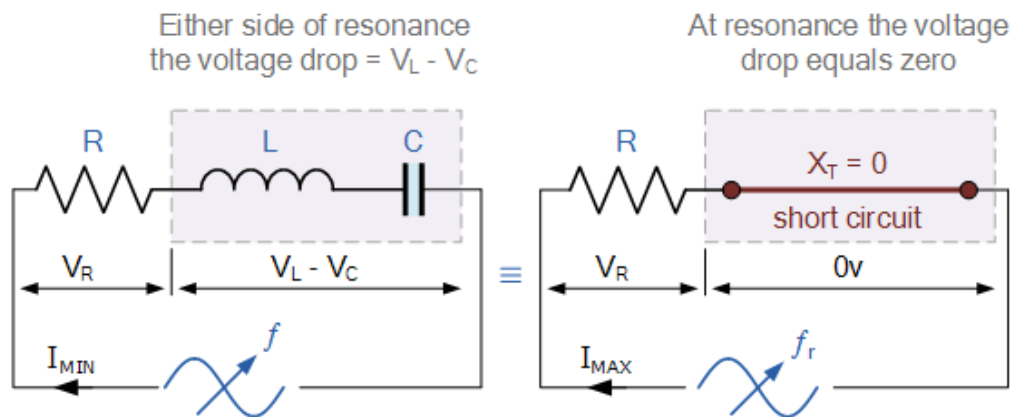
If you had to remember only one thing from the resonator, it is this one : for 1 precise frequency, the inductor and capacitor will enter in resonance du to their inductance and capacitance.

If you like maths, let's put it that way : for one precise frequency, the capacitive reactance and the inductive reactance cancels with each other, leading to a resulting impedance which is only real.

Knowing this phenomenon, we can then observe the difference between a parallel and serial resonator.

For a serial resonator, when the reactances are cancelling, the equivalent circuit of a serial capacitor/inductor is a simple wire (very low impedance) . The voltage drop accros 2 points of a wire is nil, and the current flowing into the remaining resistor is equal to the voltage drop accros the resistor divided by the current flowing into it. Therefor, as we plot the voltage and current at the resonance frequency, voltage is minimum and current maximum. In other words, current is the most needed when the inductor and capacitor forms a wire.

Series RLC Circuit at Resonance



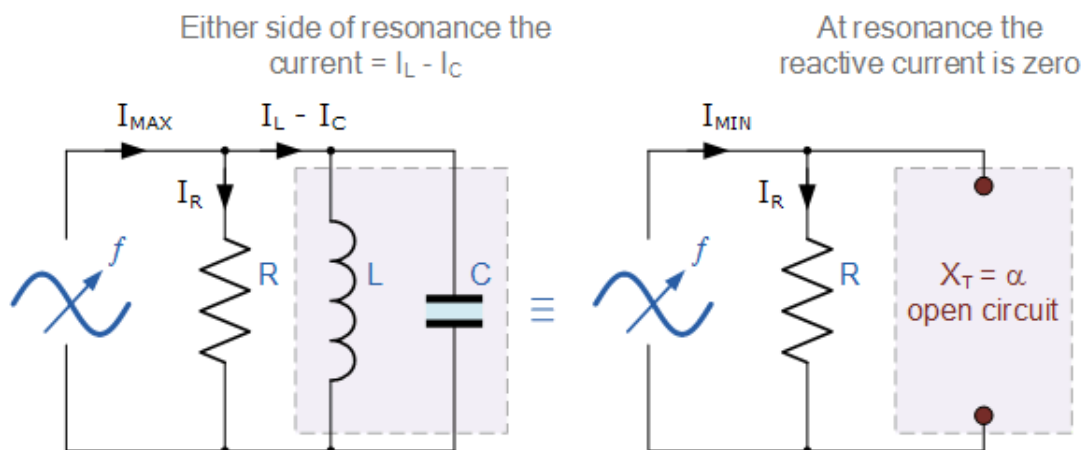
$$U = Z \cdot I, \text{ avec } Z = R \text{ et } U = V_r + 0V = V_r$$

$$I = V_r / Z \Rightarrow \text{Peak current}$$

For a resonant parallel, when the reactive parts are cancelling, the equivalent circuit is an open circuit (infinite impedance).

No current flows into the open circuit (as it does not need current), therefore the current is minimum at the resonant frequency, and as $U = Z/I$, the voltage is then at its maximum possible value.

As a recall, if an infinite impedance is put in parallel with a finite impedance, the equivalent impedance will be equal to the value of the finite impedance.



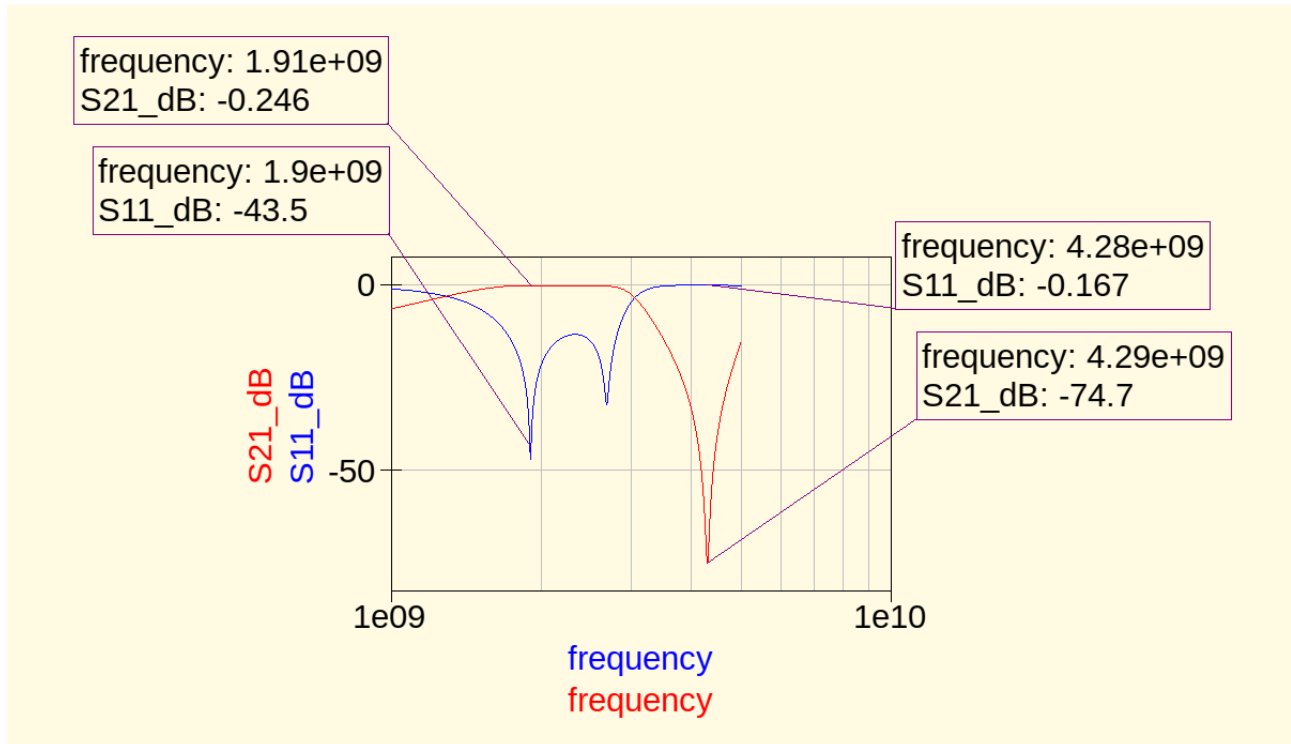
From voltages/current to S-parameters

S-Parameters are widely used in RF to characterize the good or bad behaviour of any device. Whether it is a filter, an amplifier or a piece of track. These parameters show how well the input waves are transmitted (or not) across the device. That's their only goal. According to the results, impedance adaptation may be needed, or not.

From lumped elements to distributed elements

As said previously, in HF, we favored the distributed elements, as they are not parasitic elements, on the contrary of lumped elements.

Below is the simulation of a filter implanting 2 parallel resonator networks in series with each other :

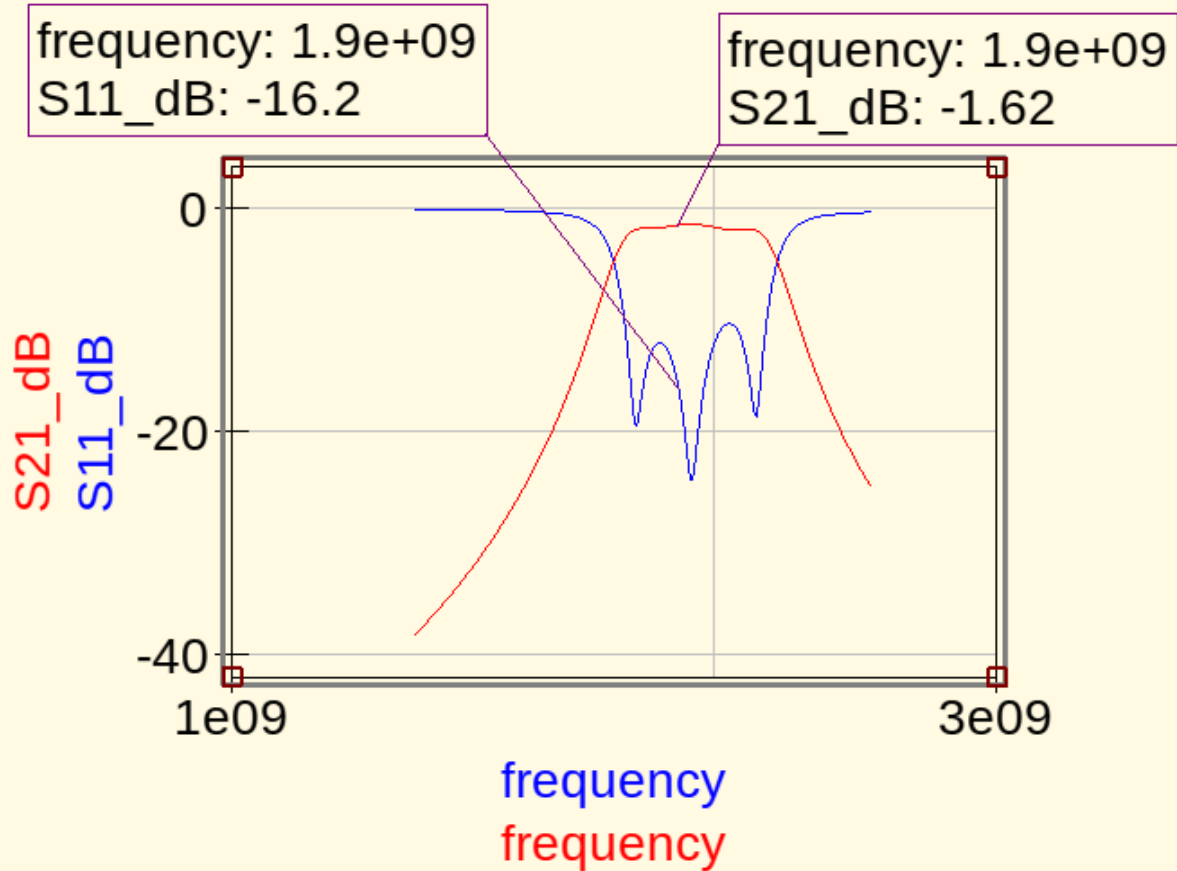


You may have already seen this filter if you have read the paper « used filter ».

From Chebyshev bandpass to coupled microstrip line

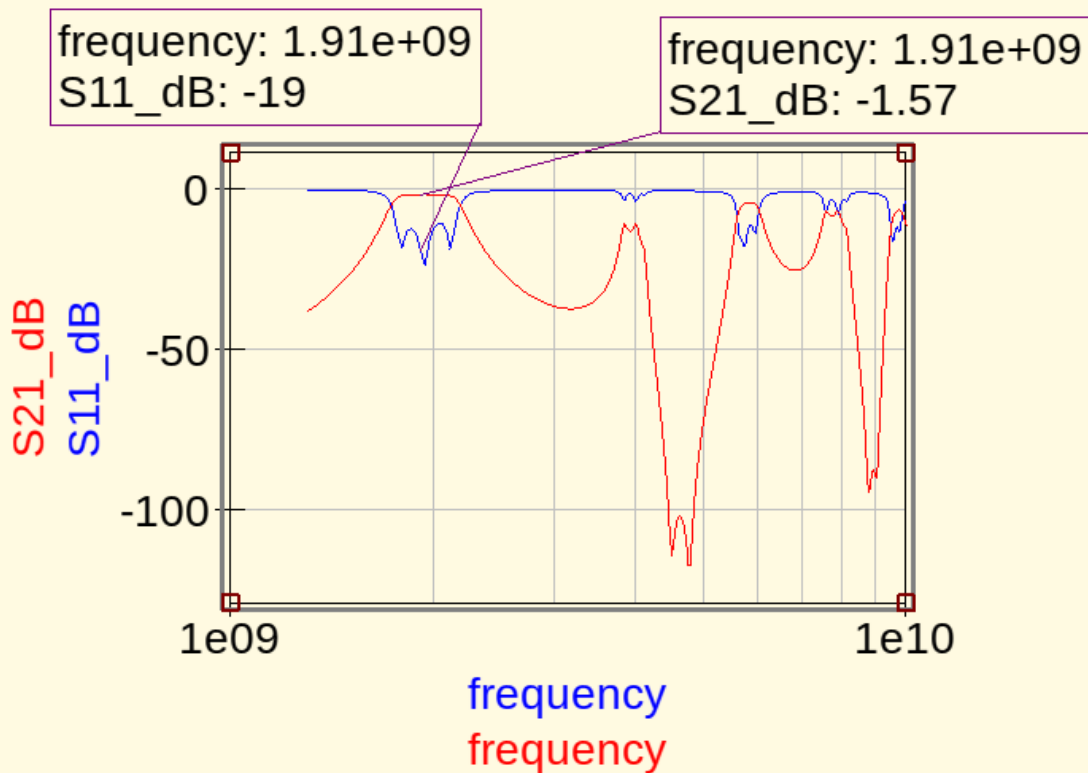
As explained in an other paper, Qucs allows to build in a really easy way a bandpass filter. For example a Chebyshev bandpass filter, $f_1 = 1.7\text{GHz}$ and $f_2 = 2.1\text{GHz}$.

Voici le résultat en simulation :



Return loss is correct and not much gain is lost when travelling through the filter (around 1/4W).

For the sake of curiosity, here is the behaviour of the filter in higher frequency :



We can clearly see that the filter is a nice stopband filter around 4.7 GHz.

How it works

Coupled microstrip line are basically 2 pieces of tracks facing each other. They are separated by a tiny space, share same width and length. What we are calculating are what we call the odd/even mode impedances of the tracks. Even mode when both tracks are polarised in the same way and odd mode when polarised in a contrary sense. These phenomenon is linked to the fact that given an electromagnetic field is radiated from the tracks, and that they are close, then there is some kind of interaction.

First coupling structure

$$Z_0 J_1 = \sqrt{\frac{\pi \Delta}{2g_1}} \quad \text{.....11}$$

For intermediate structure

$$Z_0 J_n = \frac{\pi \Delta}{2\sqrt{g_n g_{n-1}}} \quad \text{.....12}$$

For final coupling

$$Z_0 J_{n+1} = \sqrt{\frac{\pi \Delta}{2g_n g_{n+1}}} \quad \text{.....13}$$

These formulas are the foundations in order to calculate afterward the odd/even impedances.
 Z_0 is chosen arbitrarily by me. A thumb rule is that the edges stages share the same dimensions and the middle stages share the same dimensions.

Then , we can calculate our impedances.

Here are the 2 formulas :

$$Z_{0e} = [1 + Z_0 J_{i,i+1} + (Z_0 J_{i,i+1})^2] Z_0 \quad \text{.....14}$$

$$Z_{0o} = [1 - Z_0 J_{i,i+1} + (Z_0 J_{i,i+1})^2] Z_0 \quad \text{.....15}$$

Z_0 is the characteristic impedance.

We know g_1, g_2, g_3 , Δ , w_0 .

Here, $n=3$, so 4 stages.

For stage 1 (and so last stage) : $Z_{0j1} = 0.32206$, donc $Z_{0j4} = 0.32206$. Arbitrarily , I took $Z_0 = 53.08 \Omega$.

With the previous formulas : $Z_{0e} = 70.726 \Omega$ et $Z_{0o} = 36.536 \Omega$.

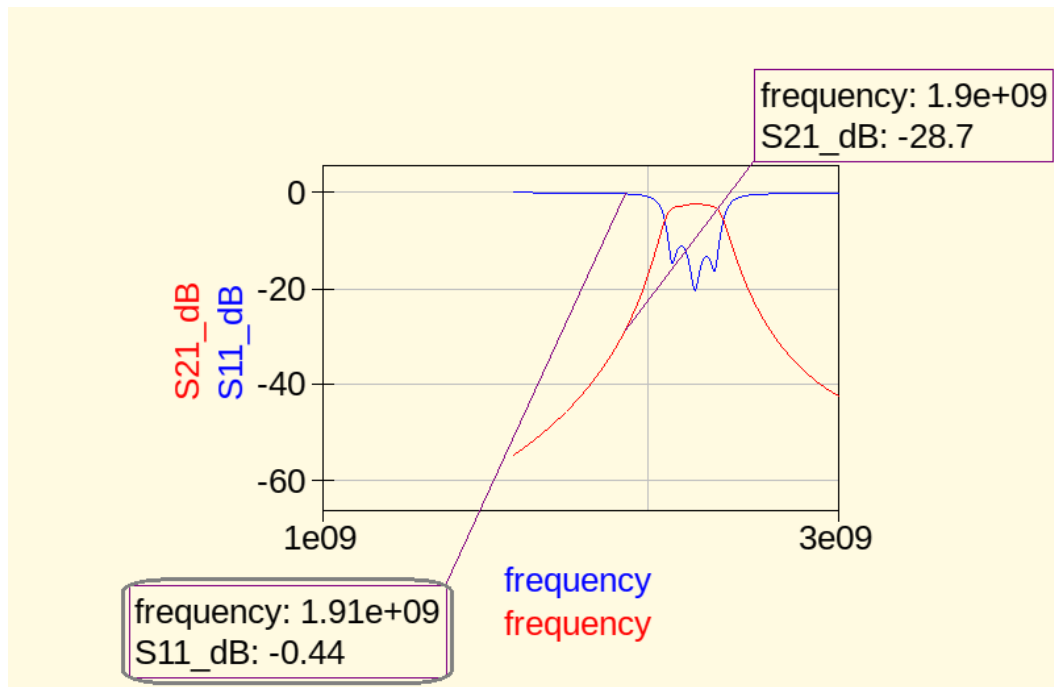
Qucs provides a coupled microstrip calculator . Here is the values he gives me : $w = 2.44019 \text{ mm}$ et $S = 0.318408 \text{ mm}$.

Passons au dimensionnement de l'étage 2 and 3: $Z_{0j2} = 0.12518$, so $Z_{0j3} = 0.12518$. Arbitrarily : $Z_0 = 51.89 \Omega$.

$Z_{0e} = 59.199 \Omega$ et $Z_{0o} = 46.208 \Omega$.

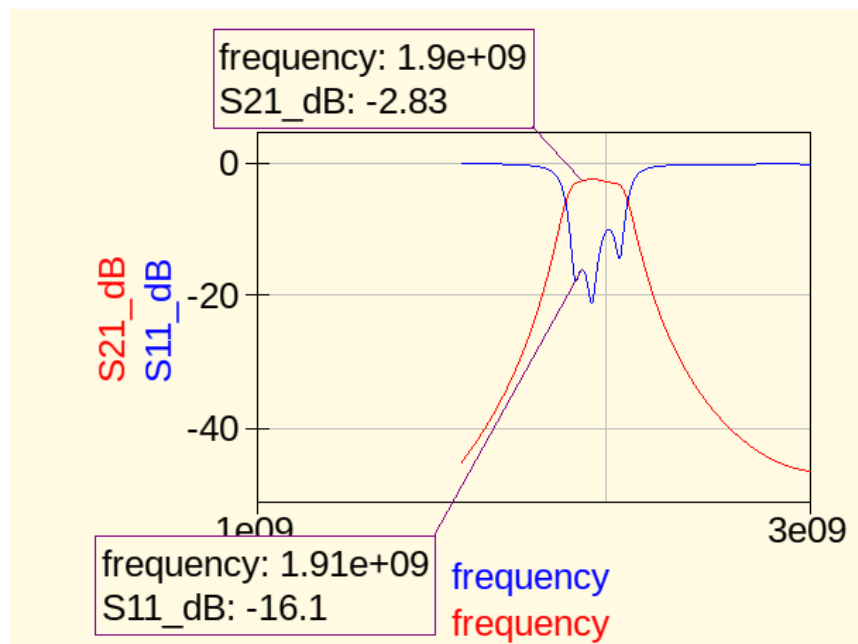
: $W = 2.72042 \text{ mm}$ et $S = 1.71481 \text{ mm}$

Let's create this custom filter, and see the simulation :



Well, it is shit. So let's replace the length (fixed at $\lambda/4$) by the ones in the Qucs filter.

Checking the simulation :



Let's note that the custom filter has a $f_1=1.8\text{GHz}$ and a $f_2=2\text{GHz}$, where the Qucs filter has $f_1=1.7\text{GHz}$ and $f_2=2.1\text{GHz}$.

Even impedance

When 2 coupled microstrip, we measure line 1 impedance when line 2 is polarised the same way

Odd impedance

When 2 coupled microstrip, we measure line 1 impedance when line 2 is reverse polarised

Differential impedance

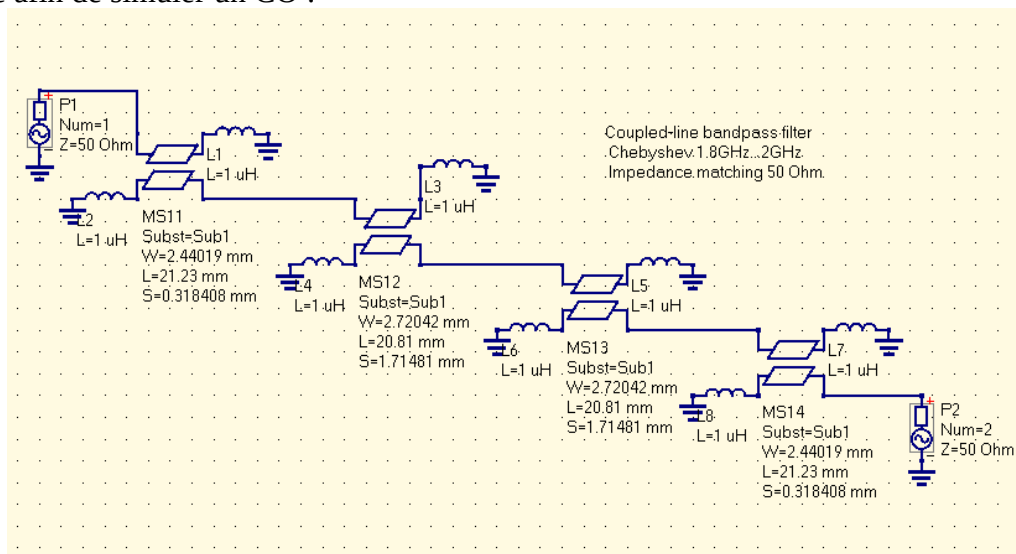
Impedance between the 2 tracks when they have different polarisation. 2 times odd impedance

Common impedance

Impedance between the tracks when same polarisation. 2 times even impedance

Paramètres S

Pour être physiquement réalisable sur PCB, j'ai rajouté à des inductances à chaque endroit nécessaire afin de simuler un CO :



Voici une partie de ses paramètres S. Ceux qui nous intéressent sont ceux à 1.9GHz :

(S11,S12,S21,S22) #GHz MA R 50

1.89e09	0.138 / 165°	0.953 / 78°	0.953 / 78°	0.138 / 165°
1.9e09	0.151 / 162°	0.952 / 74.3°	0.952 / 74.3°	0.151 / 162°
1.9e09	0.161 / 159°	0.951 / 70.7°	0.951 / 70.7°	0.161 / 159°

Reflexions are low. However, we may adapt the input and output impedances to further decrease input return loss and output return loss.